

Notice of References Cited

Application/Control No.

08/807,737

Examiner

Evan T. Pert

Applicant(s)/Patent Under
Reexamination
OHTANI ET AL.

Art Unit

2813

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U.S. PATENT DOCUMENTS

*		DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS	DOCUMENT SOURCE **	
							APS	OTHER
<input type="checkbox"/>	A	5,403,772	Apr. 1995	Zhang et al.	--	--	<input checked="" type="checkbox"/>	<input type="checkbox"/>
<input type="checkbox"/>	B	5,311,041	May. 1994	Tominaga et al.	--	--	<input checked="" type="checkbox"/>	<input type="checkbox"/>
<input type="checkbox"/>	C	5,273,920	Dec. 1993	Kwasnick et al.	--	--	<input checked="" type="checkbox"/>	<input type="checkbox"/>
<input type="checkbox"/>	D	4,915,772	Apr. 1990	Fehlner et al.	--	--	<input checked="" type="checkbox"/>	<input type="checkbox"/>
<input type="checkbox"/>	E	4,330,363	May. 1993	Biegesen et al.	--	--	<input checked="" type="checkbox"/>	<input type="checkbox"/>
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FOREIGN PATENT DOCUMENTS

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<input type="checkbox"/>	O							<input type="checkbox"/>	<input type="checkbox"/>
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<input type="checkbox"/>	T							<input type="checkbox"/>	<input type="checkbox"/>

NON-PATENT DOCUMENTS

*		DOCUMENT (Including Author, Title Date, Source, and Pertinent Pages)	DOCUMENT SOURCE **	
			APS	OTHER
<input type="checkbox"/>	U	B.C. Ahn et al., "Batch-Processing of High-Performance Amorphous-Silicon/Silicon Nitride Thin-Film Transistors", Oct. 1991, IEEE Display Research Conference, pages 85-88.	<input type="checkbox"/>	<input type="checkbox"/>
<input type="checkbox"/>	V	Sera et al., "High-Performance TFTs Fabricated by XeCl Excimer Laser Annealing of Hydrogenated Amorphous-Silicon Film", 1989, IEEE Transactions on Electron Devices, Vol. 36, No. 12, pages 2868-2872.	<input type="checkbox"/>	<input type="checkbox"/>
<input type="checkbox"/>	W	Zhang et al., "KrF Excimer Laser Annealed TFT with Very High Field-Effect Mobility of 329 cm ² /Vs", 1992, IEEE Electron Device Letters, Vol. 13, No. 5, pages 297-299	<input type="checkbox"/>	<input type="checkbox"/>
<input type="checkbox"/>	X		<input type="checkbox"/>	<input type="checkbox"/>

*A copy of this reference is not being furnished with this Office action. (See Manual of Patent Examining Procedure, Section 707.05(a).)

**APS encompasses any electronic search i.e. text, image, and Commercial Databases.

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